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### 3. Ordering information

Table 2. Ordering information								
Type number	Package							
	Name	Description	Version					
BTA316-600B	SC-46	plastic single-ended package; heatsink mounted; 1 mounting hole; 3-lead	SOT78					
BTA316-600C		TO-220AB						
BTA316-800B								
BTA316-800C								

## 4. Limiting values

#### Table 3.Limiting values

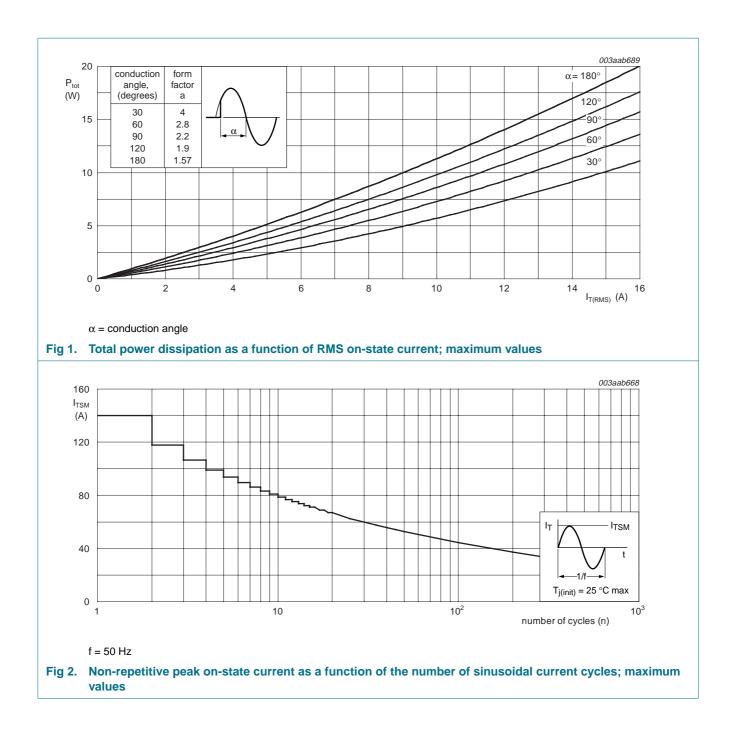
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>DRM</sub>	repetitive peak off-state voltage	BTA316-600B; BTA316-600C	<u>[1]</u> _	600	V
		BTA316-800B; BTA316-800C	-	800	V
I <sub>T(RMS)</sub>	RMS on-state current	full sine wave; T <sub>mb</sub> ≤ 101 °C; see <u>Figure 4</u> and <u>5</u>	-	16	А
I <sub>TSM</sub>	non-repetitive peak on-state current	full sine wave; $T_j = 25 \text{ °C prior to}$ surge; see <u>Figure 2</u> and <u>3</u>			
		t = 20 ms	-	140	А
		t = 16.7 ms	-	150	А
l <sup>2</sup> t	I <sup>2</sup> t for fusing	t = 10 ms	-	98	A <sup>2</sup> s
dl <sub>T</sub> /dt	rate of rise of on-state current	$I_{TM} = 20 \text{ A}; I_G = 0.2 \text{ A};$ $dI_G/dt = 0.2 \text{ A}/\mu \text{s}$	-	100	A/μs
I <sub>GM</sub>	peak gate current		-	2	А
P <sub>GM</sub>	peak gate power		-	5	W
P <sub>G(AV)</sub>	average gate power	over any 20 ms period	-	0.5	W
T <sub>stg</sub>	storage temperature		-40	+150	°C
T <sub>i</sub>	junction temperature		-	125	°C

[1] Although not recommended, off-state voltages up to 800 V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 15 A/µs.

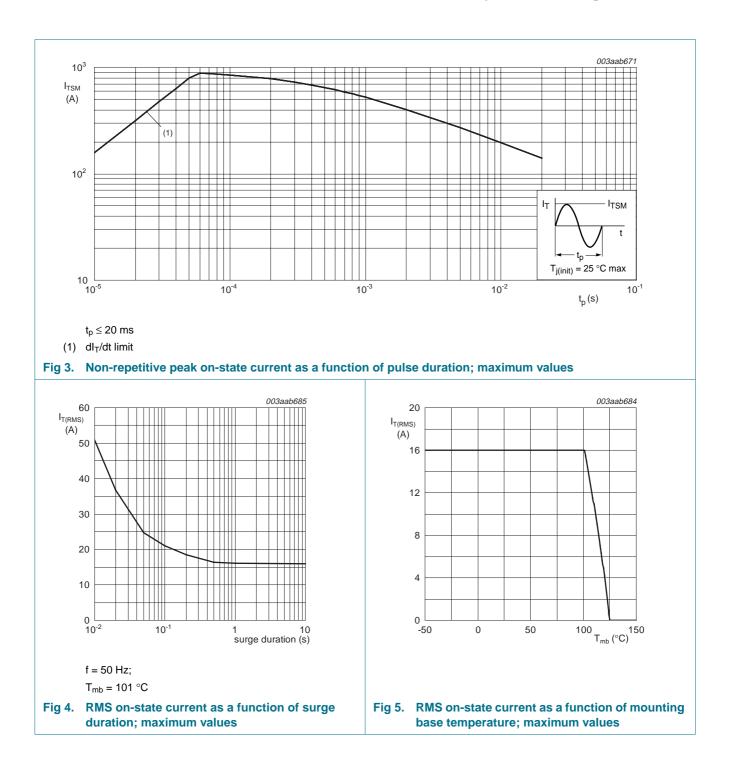
## BTA316 series B and C

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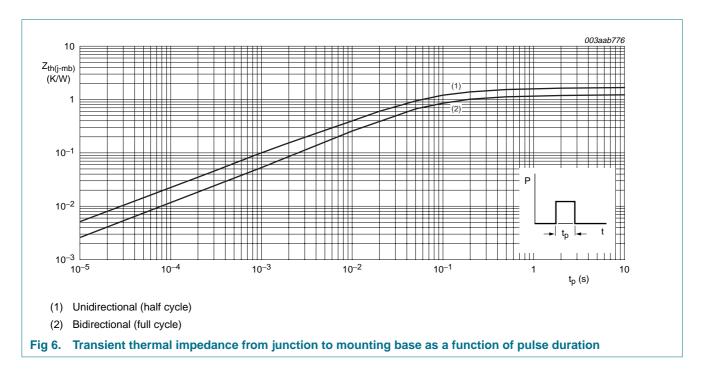
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### 5. Thermal characteristics

Table 4.	Thermal characteristics						
Symbol	Parameter	Conditions	Min	Тур	Max	Unit	
R <sub>th(j-mb)</sub>	thermal resistance from junction to	half cycle; see Figure 6	-	-	1.7	K/W	
	mounting base	full cycle; see Figure 6	-	-	1.2	K/W	
R <sub>th(j-a)</sub>	thermal resistance from junction to ambient	in free air	-	60	-	K/W	



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### 6. Static characteristics

#### Table 5. Static characteristics

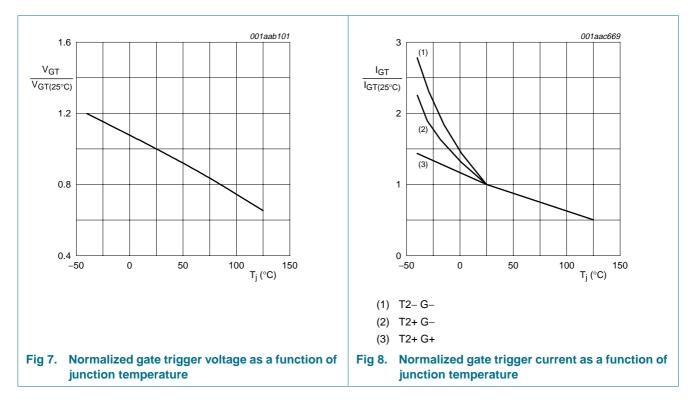
 $T_i = 25 \circ C$  unless otherwise specified.

Symbol	Parameter	Conditions		FA316-6 FA316-8			BTA316-600C BTA316-800C			
			Min	Тур	Max	Min	Тур	Max		
I <sub>GT</sub>	gate trigger	$V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ see } \frac{\text{Figure 8}}{100000000000000000000000000000000000$								
	current	T2+ G+	2	-	50	2	-	35	mA	
		T2+ G–	2	-	50	2	-	35	mA	
		T2- G-	2	-	50	2	-	35	mA	
١L	latching current	$V_D = 12 \text{ V}; \text{ I}_{GT} = 0.1 \text{ A}; \text{ see } \frac{\text{Figure } 10}{100000000000000000000000000000000$								
		T2+ G+	-	-	60	-	-	50	mA	
		T2+ G–	-	-	90	-	-	60	mA	
		T2- G-	-	-	60	-	-	50	mA	
I <sub>H</sub>	holding current	$V_D = 12 \text{ V}; \text{ I}_{GT} = 0.1 \text{ A}; \text{ see } \frac{\text{Figure } 11}{100000000000000000000000000000000$	-	-	60	-	-	35	mA	
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 18 A; see <u>Figure 9</u>	-	1.3	1.5	-	1.3	1.5	V	
V <sub>GT</sub>	gate trigger	$V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ see } \frac{\text{Figure 7}}{100000000000000000000000000000000000$	-	0.8	1.5	-	0.8	1.5	V	
	voltage	$V_D = 400 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ T}_j = 125 \ ^\circ\text{C}$	0.25	0.4	-	0.25	0.4	-	V	
I <sub>D</sub>	off-state current	$V_D = V_{DRM(max)}; T_j = 125 \ ^{\circ}C$	-	0.1	0.5	-	0.1	0.5	mA	

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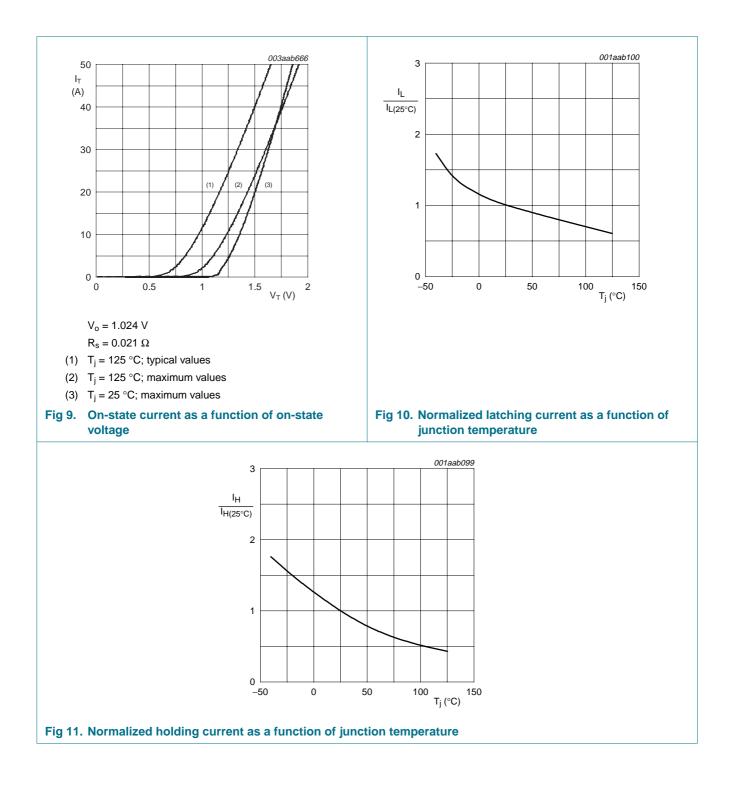
### 7. Dynamic characteristics

Table 6.	Dynamic cha	racteristics							
Symbol	Parameter	Conditions		A316-6 A316-8		B1 B1	Unit		
			Min	Тур	Max	Min	Тур	Max	
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM} = 0.67 \times V_{DRM(max)}$ ; $T_j = 125 \text{ °C}$ ; exponential waveform; gate open circuit	1000	-	-	500	-	-	V/µs
dl <sub>com</sub> /dt	rate of change of commutating current	$V_{DM}$ = 400 V; T <sub>j</sub> = 125 °C; I <sub>T(RMS)</sub> = 16 A; without snubber; gate open circuit	20	-	-	15	-	-	A/ms
t <sub>gt</sub>	gate-controlled turn-on time	$\begin{split} I_{TM} &= 20 \text{ A};  V_D = V_{DRM(max)};  I_G = 0.1 \text{ A}; \\ dI_G/dt &= 5  A/\mu s \end{split}$	-	2	-	-	2	-	μs
	turn-on time	$dI_G/dt = 5 A/\mu S$							



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## 8. Package outline

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mm	4.7 4.1	1.40 1.25	0.9 0.6	1.45 1.00	0.7 0.4	16.0 15.2	6.6 5.9	10.3 9.7	2.54	15.0 12.8	3.30 2.79	3.0	3.8 3.5	3.0 2.7	2.6 2.2	
ou	4.1 TLINE		0.6	1.00		15.2	5.9	9.7	2.54	12.8	2.79	3.0	3.5 EUR	2.7 OPEAN	2.2	ISSUE DATE
VERSION			IE	C		JEDEC JEITA							PROJECTION		4	
														30		05-03-22

#### Fig 12. Package outline SOT78 (3-lead TO-220AB)

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Product data sheet

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## 9. Revision history

Table 7.         Revision history	у			
Document ID	Release date	Data sheet status	Change notice	Supersedes
BTA316_SER_B_C_1	20070411	Product data sheet	-	-

BTA316\_SER\_B\_C\_1

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### **10. Legal information**

#### **10.1** Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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